

N-Channel 150-V (D-S) MOSFET

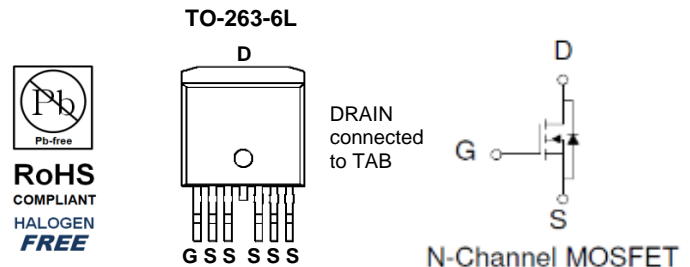
Key Features:

- Low $r_{DS(on)}$ trench technology
- Low thermal impedance
- Fast switching speed

Typical Applications:

- LED Inverter Circuits
- Inrush Limiter and Hot Swap Circuits
- 48V-Input DC/DC Conversion Circuits

PRODUCT SUMMARY		
V_{DS} (V)	$r_{DS(on)}$ (m Ω)	I_D (A)
150	21 @ $V_{GS} = 10V$	90 ^a
	26 @ $V_{GS} = 6.5V$	



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ C$ UNLESS OTHERWISE NOTED)				
Parameter		Symbol	Limit	Units
Drain-Source Voltage		V_{DS}	150	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current ^a	$T_C = 25^\circ C$	I_D	90	A
Pulsed Drain Current ^b		I_{DM}	360	
Continuous Source Current (Diode Conduction) ^a	$T_C = 25^\circ C$	I_S	90	A
Power Dissipation ^a	$T_C = 25^\circ C$	P_D	300	W
Operating Junction and Storage Temperature Range		T_J, T_{stg}	-55 to 175	$^\circ C$

THERMAL RESISTANCE RATINGS			
Parameter	Symbol	Maximum	Units
Maximum Junction-to-Ambient ^c	$R_{\theta JA}$	62.5	$^\circ C/W$
Maximum Junction-to-Case	$R_{\theta JC}$	0.5	

Notes

- Package Limited
- Pulse width limited by maximum junction temperature
- Surface Mounted on 1" x 1" FR4 Board.

Electrical Characteristics

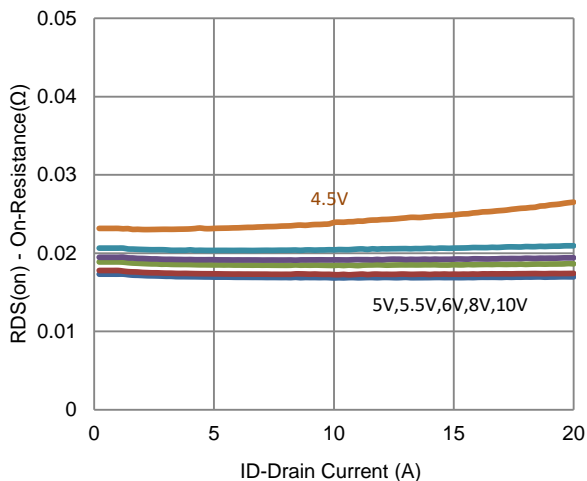
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static						
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1			V
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 120 V, V_{GS} = 0 V$			1	uA
		$V_{DS} = 120 V, V_{GS} = 0 V, T_J = 55^\circ C$			10	
On-State Drain Current ^a	$I_{D(on)}$	$V_{DS} = 5 V, V_{GS} = 10 V$	110			A
Drain-Source On-Resistance ^a	$r_{DS(on)}$	$V_{GS} = 10 V, I_D = 45 A$			21	mΩ
		$V_{GS} = 5.5 V, I_D = 40 A$			26	
Forward Transconductance ^a	g_{fs}	$V_{DS} = 15 V, I_D = 45 A$		56		S
Diode Forward Voltage ^a	V_{SD}	$I_S = 45 A, V_{GS} = 0 V$		0.94		V
Dynamic ^b						
Total Gate Charge	Q_g	$V_{DS} = 75 V, V_{GS} = 5.5 V,$ $I_D = 20 A$		28		nC
Gate-Source Charge	Q_{gs}			11		
Gate-Drain Charge	Q_{gd}			13		
Turn-On Delay Time	$t_{d(on)}$	$V_{DS} = 75 V, R_L = 3.8 \Omega,$ $I_D = 20 A,$ $V_{GEN} = 10 V, R_{GEN} = 6 \Omega$		27		ns
Rise Time	t_r			28		
Turn-Off Delay Time	$t_{d(off)}$			60		
Fall Time	t_f			40		
Input Capacitance	C_{iss}	$V_{DS} = 50 V, V_{GS} = 0 V, f = 1 Mhz$		2330		pF
Output Capacitance	C_{oss}			235		
Reverse Transfer Capacitance	C_{rss}			171		

Notes

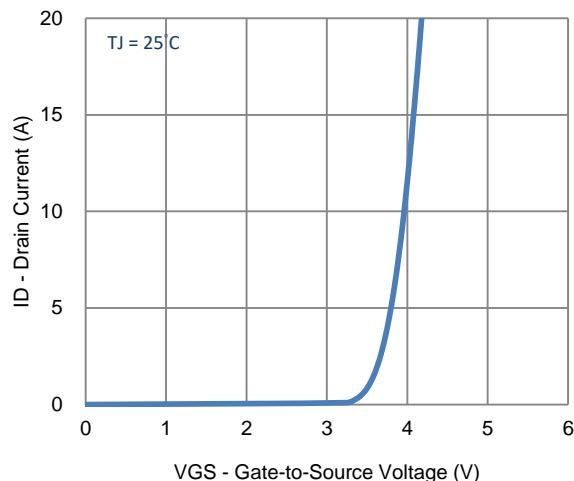
- Pulse test: PW ≤ 300us duty cycle ≤ 2%.
- Guaranteed by design, not subject to production testing.

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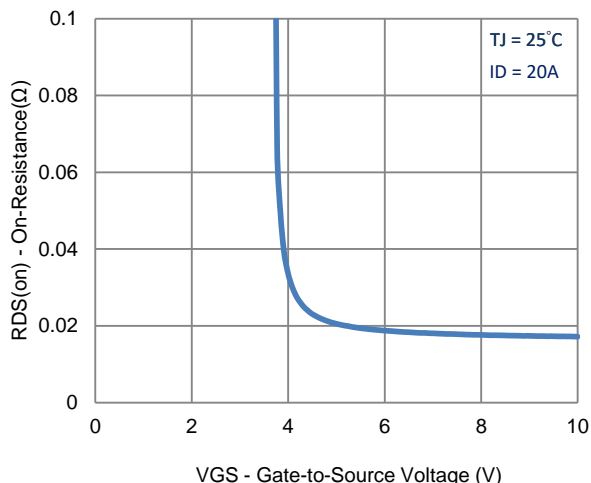
Typical Electrical Characteristics



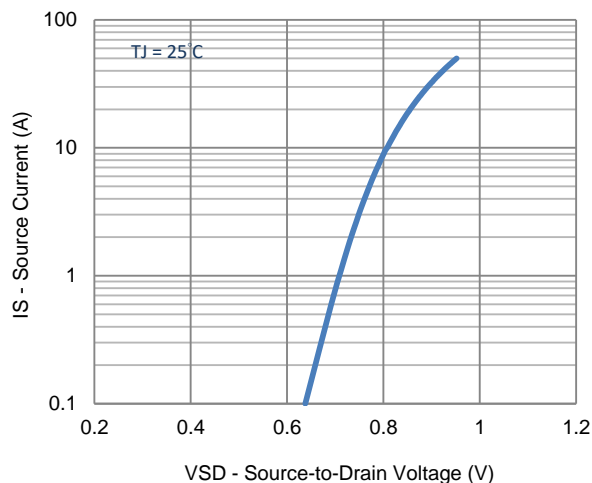
1. On-Resistance vs. Drain Current



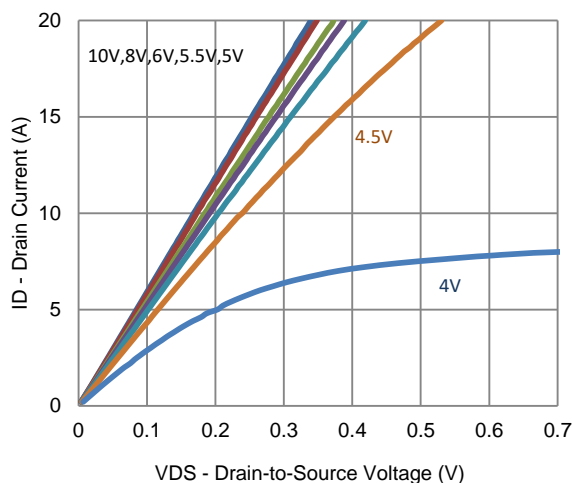
2. Transfer Characteristics



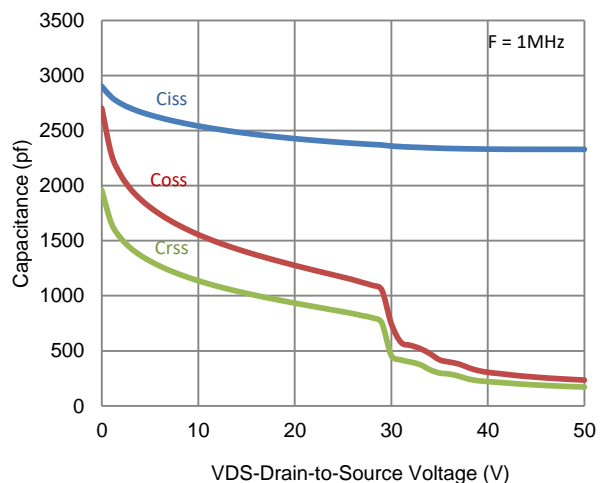
3. On-Resistance vs. Gate-to-Source Voltage



4. Drain-to-Source Forward Voltage

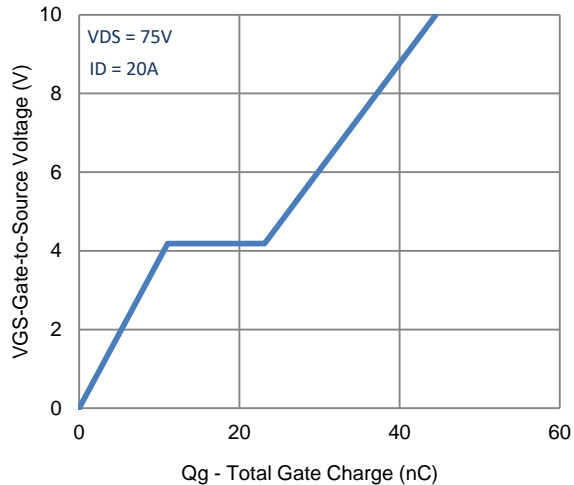


5. Output Characteristics

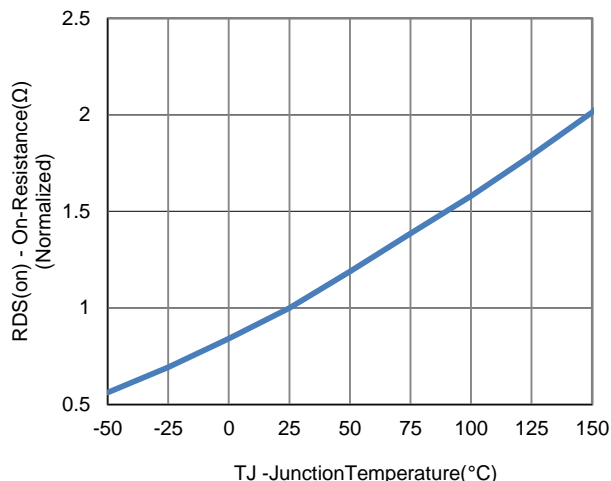


6. Capacitance

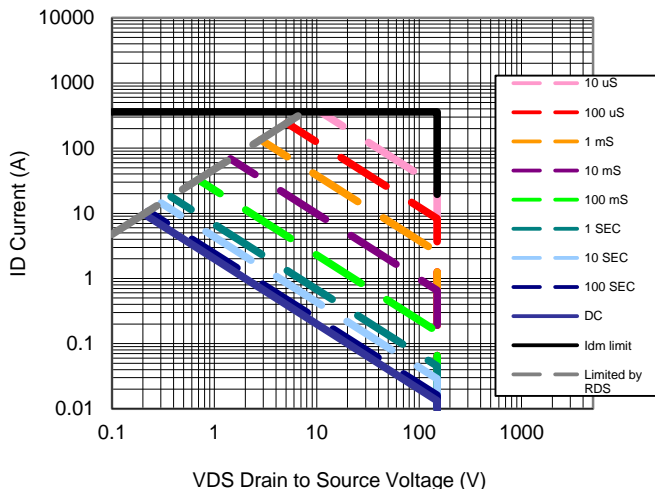
Typical Electrical Characteristics



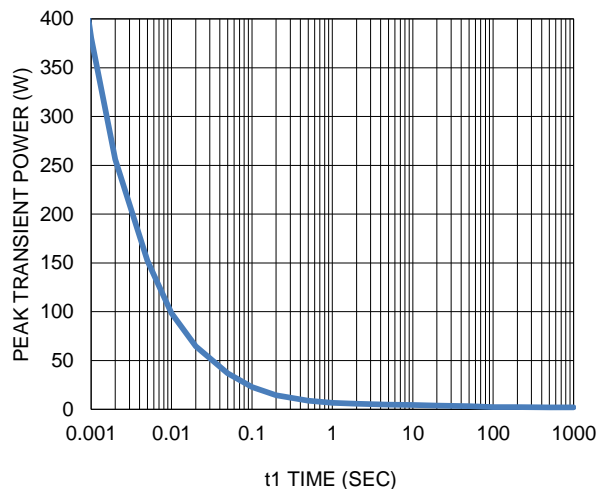
7. Gate Charge



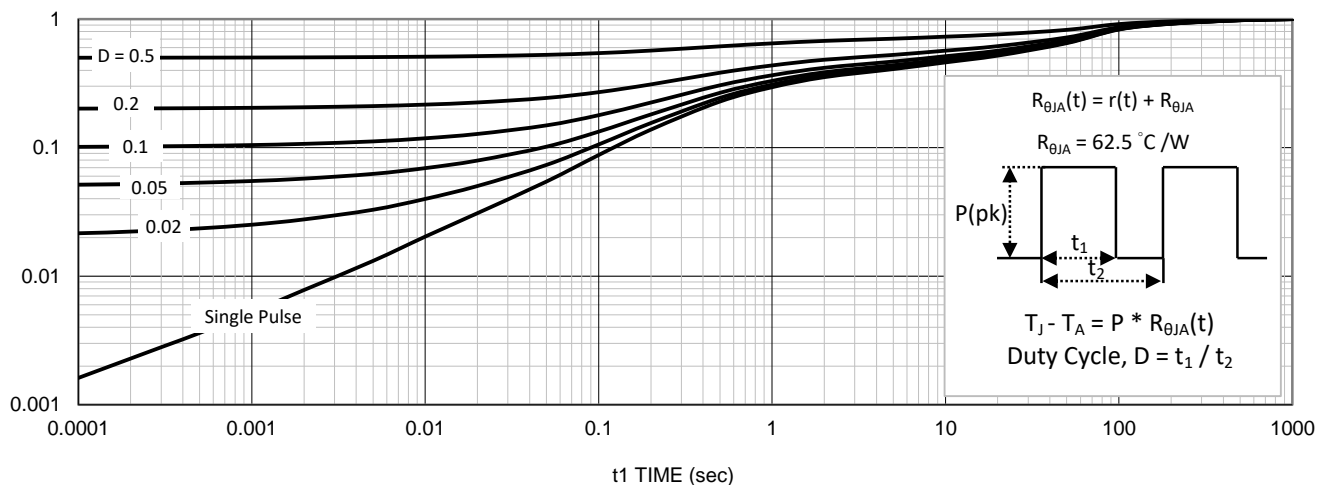
8. Normalized On-Resistance Vs Junction Temperature



9. Safe Operating Area

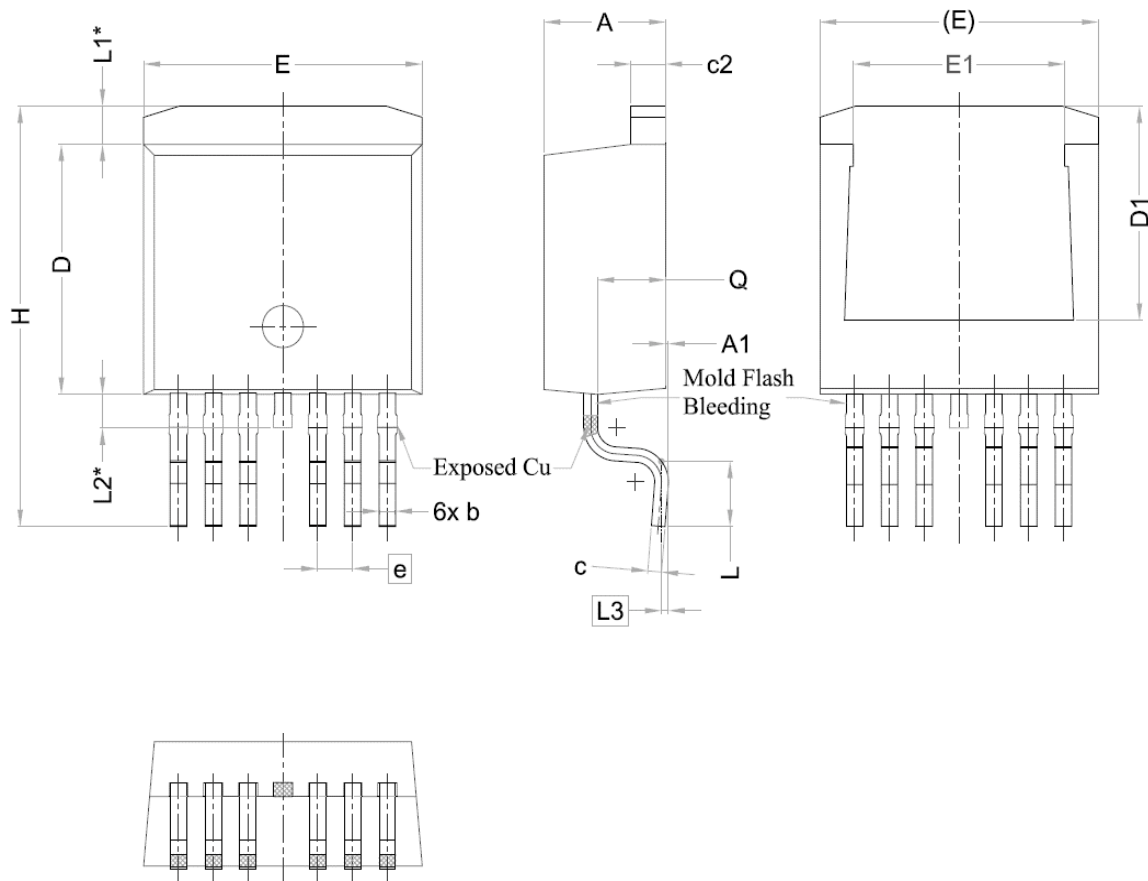


10. Single Pulse Maximum Power Dissipation



11. Normalized Thermal Transient Junction to Ambient

Package Information



SYMBOL	DIMENSIONS		
	MIN.	NOM.	MAX.
A	4.24	4.44	4.64
A1	0.00	0.10	0.25
b	0.50	0.60	0.70
c	0.40	0.50	0.60
c2	1.15	1.27	1.40
D	8.82	8.92	9.02
D1	6.86	7.65	—
E	9.96	10.16	10.36
E1	6.89	7.77	7.89
e	1.27 BSC		
H	14.61	15.00	15.88
L	1.78	2.32	2.79
L1	1.36 REF.		
L2	1.20 REF.		
L3	0.25 BSC		
Q	2.30	2.48	2.70